3

## ELECTRONIC SCIENCE

Paper – II

- 1. Silicon crystal grows into
  - (A) Zinc blende structure
  - (B) Diamond structure
  - (C) Wurtzite structure
  - (D) None of these.
- 2. The Fermi level of a degenerate *n*-type semiconductor lies
  - (A) near the conduction band edge in the band gap
  - (B) at the middle of the band gap
  - (C) inside the conduction band
  - (D) anywhere in the band gap.
- 3. In a *p*-*n* junction diode, the diffusion and drift currents are caused by
  - (A) all minority carriers
  - (B) all majority carriers
  - (C) all majority carriers for diffusion current and all minority carriers for drift current
  - (D) all majority carriers for drift current and all minority carriers for diffusion current.
- 4. The etchant for  $SiO_2$  in IC technology is
  - (A) HCl
  - (B) Acetic acid
  - (C) Formaldehyde
  - (D) HF.
- 5. The I-V characteristics of a practical *p*-*n* junction is best expressed by
  - (A)  $I = K(V V_r), V_r = \text{cut in}, K = \text{constant}$

(B) 
$$I = I_0 \left( e^{eV/\eta kT} - 1 \right), \eta > 1$$

(C) 
$$I = I_0 \left( e^{eV/kT} - 1 \right)$$

(D) 
$$I = I_0 \left( e^{eV/kT} + 1 \right).$$

4

- 6. In a linear network, the ratio of voltage excitation to current response is unaltered when the positions of excitation and response are interchanged. This follows from
  - (A) Principle of superposition
  - Thevenin theorem (B)
  - (C) Reciprocity theorem
  - (D) None of these.
- 7. If  $f_1$  and  $f_2$  are the lower and upper half power frequencies of a RLC circuit and  $f_0$  is the frequency of resonance then the selectivity of RLC circuit is given by

(A) 
$$\frac{f_2 - f_0}{f_1 - f_0}$$
  
(B)  $\frac{f_2 - f_1}{2f_0}$   
(C)  $\frac{f_2 - f_1}{f_1 - f_0}$   
(D)  $\frac{f_2 - f_1}{f_0}$ .

- 8. A parabolic function when differentiated yields
  - (A) ramp function
  - (B) unit ramp function
  - (C) exponential function
  - (D) unit impulse function.
- 9. If the input voltage of a bridge rectifier is  $V_m \sin \omega t$ , then the peak inverse voltage (PIV) is
  - (A)  $V_m$
  - $2V_m$ (B)
  - (C)  $\frac{2V_m}{\pi}$  $\frac{V_m}{2}$ .
  - (D)
- The inverse of Laplace Transform of  $\frac{s+4}{2s^2+5s+3}$  is equal to 10.
  - (A)  $\frac{1}{2} \left[ 6 \exp(-t) 5 \exp(3t/2) \right]$
  - (B)  $\frac{1}{2} \left[ 6 \exp(-t) 5 \exp(-3t/2) \right]$
  - (C)  $\frac{1}{2} \left[ 6 \exp(t) 5 \exp(-3t/2) \right]$
  - (D)  $\frac{1}{2} \left[ 6 \exp(-t) + 5 \exp(-3t/2) \right].$

- 11. The action of JFET in its equivalent circuit can be represented by
  - (A) current controlled current source
  - (B) current controlled voltage source
  - (C) voltage controlled voltage source
  - (D) voltage controlled current source.
- 12. To solve the differential equation  $\frac{d^2v}{dt^2} 2\frac{dv}{dt} + v_1 = 0$ , involving voltages v(t) and  $v_1$ , an OPAMP circuit requires at least
  - (A) two OPAMP differentiators and one OPAMP adder
  - (B) one OPAMP integrator and two OPAMP adders
  - (C) two OPAMP integrators and one OPAMP adder
  - (D) one OPAMP integrator, one OPAMP differentiator and one OPAMP adder.
- 13. In the first stage inside the OPAMP-IC, external inputs are connected to the circuits which are
  - (A) phase-splitter amplifier
  - (B) difference amplifier
  - (C) R-C coupled amplifier
  - (D) emitter follower.
- 14. In the low frequency equivalent circuit of a MOSFET
  - (A) *G* is connected to *D* by a capacitor
  - (B) *G* is connected to *D* by a resistor
  - (C) *G* is not connected to *D*
  - (D) G is connected to D with a current generator

G = Gate, D = Drain

- 15. One 4-to-16 decoder with active low outputs needs some additional logic gates to design a comparator to two 2-bit binary numbers. Those additional gates are
  - (A) OR gates
  - (B) NAND gates
  - (C) EX-OR gates
  - (D) NOR gates.

6

- 16. The Q output becomes  $\overline{Q}$  for a T flip-flop when the T input is
  - (A) 1
  - (B) 0
  - (C) 0 or 1
  - (D) 1 or 0.
- 17. "Multiplexing" means
  - (A) one to many
  - (B) one to one
  - (C) many to many
  - (D) many to one.
- 18. The circuit in the figure is based on *n*-channel MOSFETS. For positive logic, the circuit works as a



- (A) NAND gate
- (B) OR gate
- (C) NOR gate
- (D) AND gate.
- 19. 1 MB memory in computer technology means
  - (A) 1048576 bytes
  - (B) 1024000 bytes
  - (C) 1000024 bytes
  - (D) 1000000 bytes.

20. When the following program segment is executed in a 8085 CPU based system, then the content of Reg A

LXI D, 9000H DCX D

JZ 8050H MVI A, 05H

RST1

8050 H MVI A, 06 H

RST1

- (A) 05H
- (B) 06H
- (C) 00H
- (D) none of these.

21. If instruction RST-5 is written in a program, the program control will jump to location

- (A) 0020H
- (B) 0024H
- (C) 0028H
- (D) 0002H.

22. Which of the following ports of 8255 supports bi-directional data transfer function ?

- (A) Port A
- (B) Port B
- (C) Port C upper
- (D) Port C lower
- 23. Choose the correct statement :
  - (A) Instruction cycle is a part of machine cycle
  - (B) An instruction cycle can have more than one opcode fetch machine cycles
  - (C) In an execution cycle, there can be no fetch cycle
  - (D) In 8085 AD bus is time-multiplexed.
- 24. For an 8085  $\mu P$  with 5 MHz clock, what is the time required to perform the instruction LDA 8085 ?
  - (A)  $0.8 \ \mu \ sec$
  - (B)  $2 \mu$  sec
  - (C)  $2.6 \ \mu \ sec$
  - (D)  $3\cdot 2 \mu$  sec.

7

25. For a statement : Do 10 I = L, M, N, the number of iterations will be

(A)	$\left(\frac{M-L}{N}\right)$
(B)	$1 + \left(\frac{M-L}{N}\right)$
(C)	$1 - \left(\frac{M-L}{N}\right)$
(D)	$1 + \left(\frac{M+L}{N}\right).$

26. What will be the correct output statement of the following *C* program ?

/\* program \*/ #include <stdio.h> main ( )

{

printf ("%.0f\n",3.0/4.0);
printf("%.1f\n",3.0/4.0);
printf("%.2f\n", 3.0/4.0);

```
}
```

(A) 1

- 0.75 0.8
- (B) 0.750.8

0.75

- (C) 0.00.750.75
- (D) 1 0.8
  - 0.75

27. FORTRAN subroutine always

(A) follows data card

- (B) follows main program
- (C) jumps main program
- (D) succeeds main program.

- 28. A quarter-wavelength of a lossless uniform transmission line open circuited at the load end behaves as
  - (A) a perfect inductor
  - (B) a perfect capacitor
  - (C) a series tuned circuit
  - (D) a parallel tuned circuit.
- 29. To tune a microwave oscillation, *p*-*n* junction diode may be used in
  - (A) forward bias condition
  - (B) reverse bias condition
  - (C) no biasing is necessary
  - (D) all the above conditions are wrong.
- 30. An evanescent mode occurs when
  - (A) a wave is attenuated rather than propagated
  - (B) the propagation constant is purely imaginary
  - (C) m = 0 = n so that all field components vanish
  - (D) the wave frequency is the same as the cut-off frequency
- 31. What is the differential statement of Poynting's theorem connecting Poynting vector? Let S be the Poynting vector, u be the field energy density,  $\vec{E}$  be the electric field and  $\vec{j}$  be the current density.
  - (A)  $\vec{\nabla} \cdot \vec{S} + \vec{j} \cdot \vec{E} = 0$ (B)  $\vec{\nabla} \cdot \vec{S} + \frac{\partial u}{\partial t} + \vec{j} \cdot \vec{E} + IR = 0$ (C)  $\vec{\nabla} \cdot \vec{S} + \frac{\partial u}{\partial t} + \vec{j} \cdot \vec{E} = 0$ (D)  $\vec{\nabla} \cdot \vec{S} + \frac{\partial u}{\partial t} = 0$ .
- 32. The condition of no distortion in a practical transmission line in terms of primary line constants is
  - (A) RC = GL
  - (B) RL = GC
  - (C) RG = LC
  - (D) RLGC = 1

- 33. Gunn diodes are called transferred electron device because
  - (A) electrons are transferred from valence band to conduction band
  - (B) electrons are transferred from heavy hole band to light hole band
  - (C) electrons are transferred from heavy hole band to split-off band
  - (D) electrons are transferred from lower conduction band to higher conduction band.
- In a low level AM transmitter, amplifier following the modulated state must be 34.
  - (A) Class-A
  - (B) linear Class-B
  - (C) Class-C
  - (D) Class-AB.
- 35. A DSB-SC AM signal is detected using
  - (A) envelope detectors
  - (B) synchronous detectors
  - (C) limiter discriminators
  - (D) band-pass filters.
- For normal speech signal to be transmitted, the bandwidth required for PCM channel 36. would be
  - (A) 1 kHz
  - (B) 8 kHz
  - (C) 16 kHz
  - (D) 64 kHz.
- Sampling theorem finds application in 37.
  - (A) Amplitude modulation
  - (B) FM
  - (C) PCM
  - (D) Phase modulation.
- 38. Which of the following semiconductor devices acts like a diode and two resistors ?
  - (A) SCR
  - (B) Diac
  - (C) Triac
  - (D) UJT.

- 39. The emission from usual light sources is
  - (A) totally coherent
  - (B) totally incoherent
  - (C) principally coherent
  - (D) principally incoherent.
- 40. Radiation emitted by a LED can be in the
  - (A) UV region
  - (B) visible region
  - (C) visible as well as in the infrared region
  - (D) only in the infrared region.
- 41. A *p-i-n* photodiode, on an average, generates one electron-hole pair per five incident photons at a  $\lambda = 0.90 \mu m$ . Assuming all the photo-generated electrons are collected, what is the quantum efficiency of the diode ?
  - (A) 20%
  - (B) 30%
  - (C) 40%
  - (D) 50%.
- 42. Given that Germanium (Ge) has a band gap of 0.67 eV, what is the wavelength that will be absorbed by it ?
  - (A) 7,080 nm
  - (B) 4,560 nm
  - (C) 1,850 nm
  - (D) 1,100 nm.
- 43. Erbium-doped fibre amplifier repeaters operate at which of the following wavelength windows ?
  - (A) Low dispersion window (  $\sim 1.3 \ \mu m$  )
  - (B) Low attenuation window (  $\sim 1.55~\mu m$  )
  - (C) Both of the above windows
  - (D) None of these.
- 44. The material for making an efficient LED should be
  - (A) an indirect band gap type semiconductor
  - (B) a direct band gap type semiconductor
  - (C) a metal
  - (D) an insulator.

- 45. Which of the following materials is not suitable for making an LED ?
  - (A) GaAs
  - (B) Silicon
  - (C) InGaAsP
  - (D) GaAlAs.
- 46. Laser action in semiconductor *p*-*n* junction is possible for
  - (A) any finite value of forward current
  - (B) any finite value of reverse current
  - (C) current producing positive gain
  - (D) current sufficient to make gain exceeding total losses.
- 47. For the characteristic equation  $s^4 + 5s^3 + 5s^2 + 4s + k = 0$ , the system is stable if k lies in the range
  - $(A) \quad 4 > k > 0$
  - (B) 80/105 > k > 0
  - (C) 2 > k > 0
  - (D) 84/25 > k > 0.
- 48. Nyquist stability criterion is based on the principle of
  - (A) arguments
  - (B) imaginary numbers
  - (C) s-plane
  - (D) conjugates.
- 49. Hall effect transducers can be used to measure
  - (A) mobility, conductivity and carrier type
  - (B) displacement, position and velocity
  - (C) position, magnetic flux and pressure
  - (D) displacement, positive and magnetic flux.
- 50. The function of the dummy strain gauge, in measurement using two strain gauges, is to
  - (A) increase the stability
  - (B) nullify the errors due to temperature
  - (C) measure the strain in both, *X* as well as *Y* directions
  - (D) increase the sensitivity of measuring system.